ASSP

TIMING EXTRACTION BANDPASS FILTER (1.5 to 100MHz)

F1/F2/F3 SERIES

■ DESCRIPTION

The F1, F2 and F3 Series were developed as timing extraction filters for primary, secondary, and tertiary digital communication devices.

This new all-solid-state bandpass filter (BPF) uses a piezoelectric with a large electromechanical coefficient (lithium tantalate: LiTaO₃). The filter has a wide bandwidth, and is very stable.

FEATURES

- Wide frequency range 1.5 to 100MHz
- Wide fractional bandwidth (%): 0.1 to 2.5
- Low insertion loss: 6dB or less
- Excellent temperature characteristics: 1.5 to 35MHz: ±400ppm or less (0 to 60°C)
 - 36 to 100MHz: -30ppm/°C (0 to 60°C)
- Small frequency deviation $\Delta f_0 < \pm 500$ ppm eliminating the need for adjustment
- · Highly reliable hermetically sealed package
- Compatible with small 14-pin DIP IC

PACKAGE



F1/F2/F3 SERIES

■ PIN ASSIGNMENT

(BOTTOM VIEW)						
		O 1 7 O				
	Ĺ	014 80				
Pin No.	Pin name	Description				
Pin No.	Pin name					
		Description				
1	IN	Description Input pin				

■ MAXIMUM RATINGS

Item	Symbol	Rating	Unit
Operating temperature	Ta	-20 to 80	°C
Storage temperature	Tstg	-40 to 80	°C
Insulation resistance	IR	100 (100V DC)	MΩ
Frequency range	_	1.5 to 100	MHz

■ RECOMMENDED OPERATING CONDITIONS

ltem	Symbol	Rating	Unit
Operating temperature	Ta	0 to 70	°C

F1/F2/F3 SERIES

■ STANDARD FREQUENCY

Series	Standard frequency	Application	Remarks
	1.544MHz	For the U.S. and Japan (primary group)	
	2.048MHz	For Europe (primary group)	
	3.088MHz	For the U.S. and Japan (primary group)	1.544 × 2
	3.152MHz	For the U.S. and Japan (primary group)	
Γ1	4.096MHz	For Europe (primary group)	2.048 × 2
F1	6.312MHz	For the U.S. and Japan (secondary group)	
	8.192MHz	For the U.S. and Japan (secondary group)	
	8.448MHz	For Europe (secondary group)	
	12.624MHz	For the U.S. and Japan (secondary group)	6.312×2
	16.384MHz	For the U.S. and Japan (secondary group)	8.192×2
	16.896MHz	For Europe (secondary group)	8.448 × 2
F2	32.064MHz	For Japan (tertiary group)	
	34.368MHz	For Europe (tertiary group)	
F3	44.736MHz	For the U.S. (tertiary group)	

■ ELECTRICAL CHARACTERISTICS

F1 Series

ltem	Symbol	Condition	Rating			Unit	Remarks
nem	Symbol	Condition	Min.	Typical	Max.	Onit	Remarks
Frequency deviation	Δfo		-500		+500	ppm	fo standard
Load Q	Q		1000		40		
Insertion loss	IL				6	dB	
Stop band attenuation	Aout	fo ± 10MHz	20			dB	
Frequency stability with temperature	∆f (Ta)		-400		+400	ppm	25°C standard, Ta = 0 to 70°C

F2 Series

ltem	Symbol	Condition	Rating			Unit	Remarks	
nem	Symbol	Condition	Min.	Typical	Max.	Onit	itemarks	
Frequency deviation	Δfo	_	-500		+500	ppm	fo standard	
Load Q	Q		1000		40			
Insertion loss	IL				6	dB		
Stop band attenuation	Аоит	fo ± 10MHz	20		_	dB		
Frequency stability with temperature	∆f (Ta)		-400	—	+400	ppm	25°C standard, Ta = 0 to 70°C	

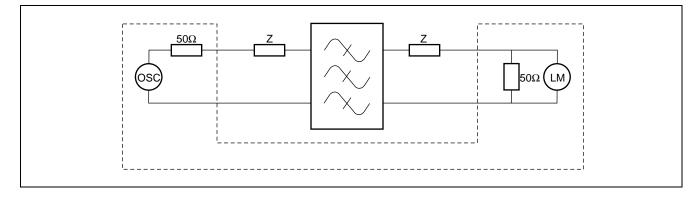
F3 Series

ltem	Symbol	Condition	Rating			Unit	Remarks	
nem	Symbol	Condition	Min.	Typical	Max.	Onit	itemarks	
Frequency deviation	Δfo	_	-500	—	+500	ppm	fo standard	
Load Q	Q		200	—	50			
Insertion loss	IL				6	dB		
Stop band attenuation	Аоит	fo ± 10MHz	20			dB		
Frequency stability with temperature	∆f (Ta)		-1350		750	ppm	25°C standard, Ta = 0 to 70°C	

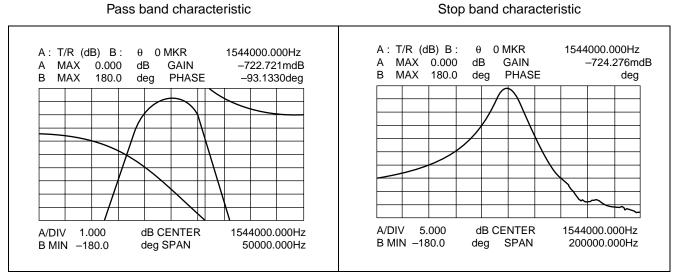
■ ELECTRICAL CHARACTERISTICS

	Ctoudoud	andard		Specification					
No.	Standard frequency (MHz)	Part number	Load Q	Insertion loss, IL (dB)	Phase rotation θ (degree)	Terminating impedance Z (Ω)			
1	1.544	FAR-F1DA-1M5440-G201	110 ±20	3 or less	-90±20	790			
2	1.544	FAR-F1DA-1M5440-G202	110 ±20	3 or less	-90±20	1000			
3	1.544	FAR-F1DA-1M5440-G203	60 ±10	3 or less	-95±10	2035/20pF			
4	1.544	FAR-F1DA-1M5440-G205	110 ±20	3 or less	-90±20	2000			
5	2.048	FAR-F1DA-2M0480-G201	40 ±10	3 or less	-90±10	2035			
6	2.048	FAR-F1DA-2M0480-G202	100 ±20	3 or less	-90±20	1000			
7	3.088	FAR-F1DA-3M0880-G201	150 ±20	3 or less	-90±20	640			
8	3.152	FAR-F1DA-3M1520-G201	85 ±15	3 or less	-90±15	1285			
9	4.096	FAR-F1DA-4M0960-G201	110 ±20	3 or less	-90±20	750			
10	6.312	FAR-F1DA-6M3120-G201	110 ±20	3 or less	-90±20	985			
11	6.312	FAR-F1DA-6M3120-G202	110 ±20	3 or less	-90±20	1000			
12	8.192	FAR-F1DA-8M1920-G201	100 ±20	3 or less	-90±20	980			
13	8.448	FAR-F1DA-8M4480-G201	110 ±20	3 or less	-90±20	980			
14	12.624	FAR-F1DA-12M624-G201	100 ±20	3 or less	-90±20	590			
15	16.384	FAR-F1DA-16M384-G201	100 ±20	3 or less	-90±20	410			
16	16.896	FAR-F1DA-16M896-G201	100 ±20	3 or less	-90±20	390			
17	32.064	FAR-F2DA-32M064-G201	100 ±10	3 or less	-90±15	100			
18	34.368	FAR-F2DA-34M368-G201	100 ±10	3 or less	-90±15	100			
19	44.736	FAR-F3DA-44M736-G201	65 ±15	6 or less	38±10	105			

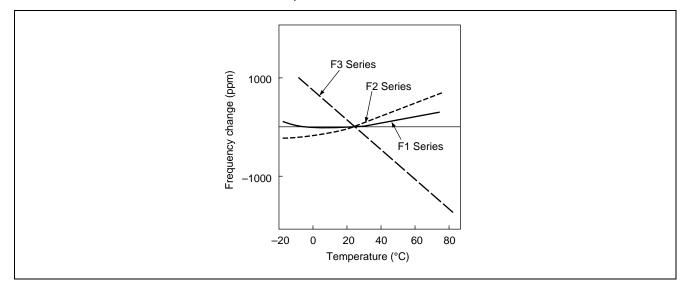
■ TEST CIRCUIT



■ CHARACTERISTICS SAMPLE

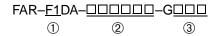


Temperature characteristic



■ PART NUMBERING SYSTEM

[Example]

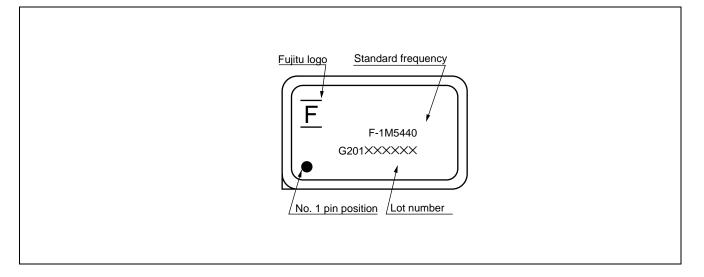


① Series designation

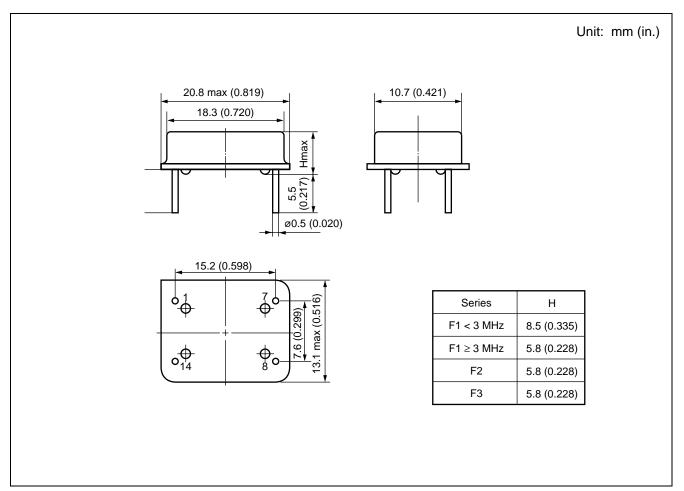
- ② Frequency designation: The standard frequency is designated in six alphanumeric characters. M is used to designate the decimal point in MHz. Refer to "ELECTRIC CHARACTERISTICS" in detail Example: 1.544MHz: 1M5440
- ③ Serial number: The serial number is assigned from 201 to 999 (201 is normal).

F1/F2/F3 SERIES

■ MARKING



■ DIMENSIONS



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